NSN 5961-01-474-3668

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-474-3668 **Inclosure Material:** Ceramic **Overall Length:** Between 1.940 inches and 2.785 inches **Overall Width:** Between 0.135 inches and 0.185 inches **Features Provided:** Hermetically sealed case Voltage Rating In Volts Per Characteristic: 45.9 breakdown voltage, dc **Current Rating Per Characteristic:** 5.00 microamperes forward current, average peak **Special Features:** Low dynamic impedance; hermetically sealed in metoxillite fused metal oxide; 1500 watt peak pulse power; 7.5 watt continuous; axial leaded; high reliability Shelf Life: N/a **Unit Of Measure: Demilitarization:** No